NSN 5961-01-083-7768 Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
Overall Length:
Between 0.560 inches and 0.625 inches
Terminal Length:
Between 0.500 inches and 0.562 inches
Overall Height:
0.190 inches
Overall Width:
0.420 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-220ab
Mounting Method:
Terminal
Terminal Circle Diameter:
Between 0.045 inches and 0.070 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
6.00 amperes forward current, total rms horsepower metric and 60.00 amperes forward current, total rms watts
Power Rating Per Characteristic:
16.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius case
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
No
Fiig:
A110a0